

MACOM PURE CARBIDE

WST41H0D Rev. V2

Features

Small Signal Gain: 15 dB @ 4 GHz

P_{SAT}: 120 W

• 28 V Operation

• High Breakdown Voltage

• High Temperature Operation

• Up to 4 GHz Operation

High Efficiency

Applications

2-Way Private Radio

• Broadband Amplifiers

Cellular Infrastructure

Test Instrumentation

 Class A, AB, Linear amplifiers suitable for OFDM, W-CDMA, EDGE, CDMA waveforms

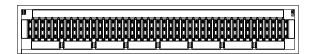
• Radar, Electronic Warfare

Description

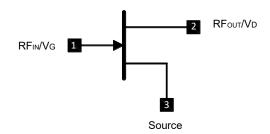
The WST41H0D is a gallium nitride (GaN) high electron mobility transistor (HEMT). GaN has superior properties compared to silicon or gallium arsenide, including higher breakdown voltage, higher saturated electron drift velocity, and higher thermal conductivity. GaN HEMTs offer greater power density and wider bandwidths compared to Si and GaAs transistors.

Ordering Information

Part Number	MOQ Increment			
WST41H0D	bulk			
WST41H0D-GP4	10 pc Gel-Pak			



Functional Schematic



Pin Configuration

Pin#	Pin Name	Function
1	RF _{IN} / V _G	RF Input / Gate
2	RF _{OUT} / V _D	RF Output / Drain
3	Source	Ground / Source

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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DC Electrical Specifications at $T_c = +25$ °C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Gate Threshold Voltage	$V_{DS} = 10 \text{ V}, I_{D} = 28.8 \text{ mA}$	V _T	-2.6	-2.0	-1.6	V
Gate Quiescent Voltage	$V_{DS} = 28 \text{ V}, I_{D} = 1000 \text{ mA}$	V_{GSQ}	_	-1.8	_	V
Saturated Drain Current	V _{GS} = 6 V, V _{GS} = 2 V	I _{DSS}	28.8	34.6	_	Α
Drain-Source Breakdown Voltage	V _{DS} = -8 V, I _D = 28.8 mA	V _{BDS}	84	_	_	V
On Resistance	V _{DS} = 0.05 V, V _{GS} = 0 V	R _{ON}	0.04	0.06	_	Ω
Gate Forward Voltage	V _{DS} = 0 V, I _D = 28.8 μA	$V_{G(ON)}$	0.4	_	_	V

Absolute Maximum Ratings^{1,2}

Parameter	Absolute Maximum			
Drain-Source Voltage	84 V			
Gate Voltage	-10, +2 V			
Drain Current	6 A			
Gate Current	15 mA			
Input Power	35 dBm			
Storage Temperature	-55C to +150°C			
Mounting Temperature	+320°C, 30 seconds			
Junction Temperature ^{3,4}	+225°C			
Operating Temperature	-40°C to +85°C			

- 1. Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.
- 3. Operating at nominal conditions with T $_{J} \leq$ +225 C will ensure MTTF > 1 x 10^6 hours.
- 4. Junction Temperature (T_J) = T_C + Θ jc * (V * I) Typical thermal resistance $(\Theta$ jc) = 0.8 °C/W for CW. a) For T_C = +25°C, T_J = 117°C @ P_{DISS} = 115 W b) For T_C = +85°C, T_J = 177°C @ P_{DISS} = 115 W

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.



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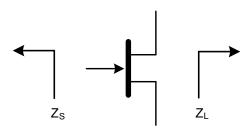
CW Load-Pull Performance: Reference Plane at Device Bond Pads

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

			Max	imum Output	Power	
Frequency	Z _{SOURCE}	$V_{DS} = 28V, I_{DQ} = 1 A, T_{C} = +25^{\circ}C, P_{SAT}$				
		Z _{LOAD}	Gain	P _{OUT}	P _{out}	η_{D}
(GHz)	(Ω)	(Ω)	(dB)	(dBm)	(W)	(%)
0.5	0.8 + j1.8	1.7 + j1.7	19.5	53.5	223.87	73
1	0.8 + j1.0	1.5 + j1.2	17.5	53.5	223.87	73
2	0.6 + j0.7	1.3 + j2.2	14.7	53.7	234.42	72
4	0.4 + j0.5	1.0 + j0.8	10.5	53.5	223.87	61
6	0.3 + j0.3	1.0 + j0.8	8.0	53.0	199.53	53

		Maximum Drain Efficiency					
Frequency	Z _{SOURCE}	V _{DS} = 28V, I _{DQ} = 1 A, T _C = +25°C, P _{SAT}					
		Z _{LOAD}	Gain	P _{OUT}	P _{OUT}	η _D	
(GHz)	(Ω)	(Ω)	(dB)	(dBm)	(W)	(%)	
0.5	0.8 + j1.8	3.6 + j3.6	18.3	52.3	169.82	86	
1	0.8 + j1.0	2.1 + j3.3	16.3	52.3	169.82	86	
2	0.6 + j0.7	1.3 + j2.2	13.0	52.0	158.49	80	
4	0.4 + j0.5	0.8 + j1.5	9.0	52.0	158.49	69	
6	0.3 + j0.3	0.7 + j1.3	7.0	52.0	158.49	61	

Impedance Reference



 Z_{SOURCE} = Measured impedance presented to the input of the device at bond pad reference plane.

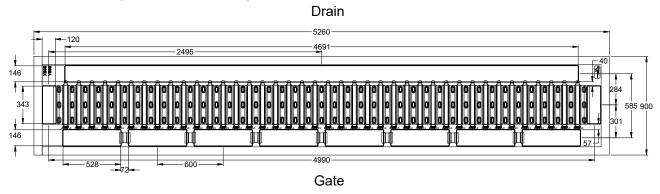
 Z_{LOAD} = Measured impedance presented to the output of the device at bond pad reference plane.



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Die Dimensions (units in microns)



Assembly Notes:

- Recommended solder is AuSn (80/20) solder. Refer to website for the Eutectic Die Bond Procedure application note.
- Vacuum Collet is the preferred method of pick-up.
- Die thickness is 3 mils.
- The backside of the die is the Source (ground) contact.
- Die back side gold plating is 5 microns thick minimum.
- Thermosonic ball or wedge bonding are the preferred connection methods.
- Gold wire must be used for connections.
- Use the die label (XXX-YYY) for correct orientation.

GaN on SiC Transistor, 120 W, 28 V DC - 4 GHz



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